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MC74HC573A

Octal 3-State Noninverting Transparent Latch

High-Performance Silicon-Gate CMOS

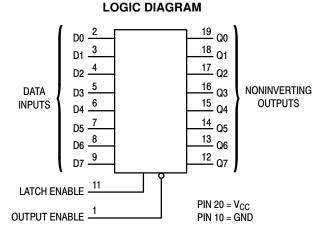
The MC74HC573A is identical in pinout to the LS573. The devices are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

These latches appear transparent to data (i.e., the outputs change asynchronously) when Latch Enable is high. When Latch Enable goes low, data meeting the setup and hold time becomes latched.

The HC573A is identical in function to the HC373A but has the data inputs on the opposite side of the package from the outputs to facilitate PC board layout.

Features

- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0 μA
- In Compliance with the JEDEC Standard No. 7.0 A Requirements
- Chip Complexity: 218 FETs or 54.5 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant



Design Criteria	Value	Units
Internal Gate Count*	54.5	ea.
Internal Gate Progation Delay	1.5	ns
Internal Gate Power Dissipation	5.0	μW
Speed Power Product	0.0075	рJ

*Equivalent to a two-input NAND gate.



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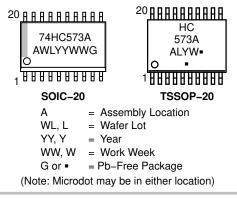
www.onsemi.com



PIN ASSIGNMENT

OUTPUT			_	
ENABLE 🚞	1	20	Þ	V _{CC}
D0 🗖	2	19		Q0
D1 🗖	3	18		Q1
D2 🗖	4	17		Q2
D3 🗖	5	16		Q3
D4 🗖	6	15		Q4
D5 🗖	7	14		Q5
D6 🗖	8	13		Q6
D7 🗖	9	12		Q7
GND 🗖	10	11		LATCH
				ENABLE

MARKING DIAGRAMS



FUNCTION TABLE

D H	Q
н	Н
L	L
Х	No Change
Х	Z
	L X

Z = High Impedance

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V _{in}	DC Input Voltage (Referenced to GND)	–0.5 to V _{CC} + 0.5	V
Vout	DC Output Voltage (Referenced to GND)	-0.5 to V _{CC} + 0.5	V
l _{in}	DC Input Current, per Pin	±20	mA
Iout	DC Output Current, per Pin	±35	mA
Icc	DC Supply Current, V _{CC} and GND Pins	±75	mA
P _D	Power Dissipation in Still Air, SOIC Package† TSSOP Package†	500 450	mW
T _{stg}	Storage Temperature	-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds (TSSOP or SOIC Package)	260	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and Vout should be constrained to the range GND \leq (V_{in} or V_{out}) \leq V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. +Derating:

SOIC Package: -7 mW/°C from 65° to 125°C

TSSOP Package: -6.1 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	2.0	6.0	V
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V _{CC}	V
T _A	Operating Temperature, All Package Types	-55	+125	°C
t _r , t _f	Input Rise and Fall Time $V_{CC} = 2.0 \text{ V}$ (Figure 1) $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$	0 0 0	1000 500 400	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

				Guaranteed Limit		mit	
Symbol	Parameter	Test Conditions	V _{CC} V	–55 to 25°C	≤ 85°C	≤125°C	Unit
V _{IH}	Minimum High-Level Input Voltage	$\label{eq:Vout} \begin{array}{l} V_{out} = 0.1 \ V \ \text{or} \ V_{CC} - 0.1 \ V \\ I_{out} \ \leq \ 20 \ \mu A \end{array}$	2.0 3.0 4.5 6.0	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	V
VIL	Maximum Low-Level Input Voltage	$\begin{array}{l} V_{out}=0.1 \ V \ \text{or} \ V_{CC}-0.1 \ V \\ I_{out} \ \leq \ 20 \ \mu A \end{array}$	2.0 3.0 4.5 6.0	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1 8	0.5 0.9 1.35 1.8	V
V _{OH}	Minimum High–Level Output Voltage	$ \begin{array}{l} V_{in} = V_{IH} \text{ or } V_{IL} \\ I_{out} \leq 20 \ \mu A \end{array} $	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		$\label{eq:Vin} \begin{array}{ll} V_{in} = V_{IH} \text{ or } V_{IL} & I_{out} \leq 2.4 \text{mA} \\ I_{out} \leq 6.0 \text{ mA} \\ I_{out} \leq 7.8 \text{ mA} \end{array}$	3.0 4.5 6.0	2.48 3.98 5.48	2.34 3.84 5.34	2.2 3.7 5.2	
V _{OL}	Maximum Low–Level Output Voltage	$\begin{array}{l} V_{out} = 0.1 \ V \ or \ V_{CC} - 0.1 \ V \\ I_{out} \ \leq \ 20 \ \mu A \end{array}$	2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		$ \begin{array}{ll} V_{in} = V_{IH} \text{ or } V_{IL} & I_{out} \leq 2.4 \text{mA} \\ I_{out} \leq 6.0 \text{ mA} \\ I_{out} \leq 7.8 \text{ mA} \end{array} $	3.0 4.5 6.0	0.26 0.26 0.26	0.33 0.33 0.33	0.4 0.4 0.4	
l _{in}	Maximum Input Leakage Current	V _{in} = V _{CC} or GND	6.0	±0.1	±1.0	±1.0	μΑ
I _{OZ}	Maximum Three-State Leakage Current	$\begin{array}{l} Output \text{ in High-Impedance State} \\ V_{\text{in}} = V_{\text{IL}} \text{ or } V_{\text{IH}} \\ V_{\text{out}} = V_{\text{CC}} \text{ or GND} \end{array}$	6.0	±0.5	±5.0	±10	μΑ
Icc	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC} \text{ or GND}$ $II_{out}I = 0 \ \mu A$	6.0	4.0	40	160	μΑ

MC74HC573A

	Parameter	V _{CC}	Guaranteed Limit			
Symbol		v	–55 to 25°C	≤ 85°C	≤125°C	Unit
t _{PLH} ,	Maximum Propagation Delay, Input D to Q	2.0	150	190	225	ns
t _{PHL}	(Figures 1 and 5)	3.0	100	140	180	
		4.5	30	38	45	
		6.0	26	33	38	
t _{PLH} ,	Maximum Propagation Delay, Latch Enable to Q	2.0	160	200	240	ns
t _{PHL}	(Figures 2 and 5)	3.0	105	145	190	
		4.5	32	40	48	
		6.0	27	34	41	
t _{PLZ} ,	Maximum Propagation Delay, Output Enable to Q	2.0	150	190	225	ns
t _{PHZ}	(Figures 3 and 6)	3.0	100	125	150	
		4.5	30	38	45	
		6.0	26	33	38	
t _{PZL} ,	Maximum Propagation Delay, Output Enable to Q	2.0	150	190	225	ns
t _{PZH}	(Figures 3 and 6)	3.0	100	125	150	
		4.5	30	38	45	
		6.0	26	33	38	
t _{TLH} ,	Maximum Output Transition Time, Any Output	2.0	60	75	90	ns
t _{THL}	(Figures 1 and 5)	3.0	27	32	36	
		4.5	12	15	18	
		6.0	10	13	15	
C _{in}	Maximum Input Capacitance		10	10	10	pF
Cout	Maximum 3-State Output Capacitance (Output in High-Imped	ance State)	15	15	15	pF
			Typical @	25°C, V _{CC}	= 5.0 V	
C _{PD}	Power Dissipation Capacitance (Per Enabled Output)*			23		pF

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6.0 \text{ ns}$)

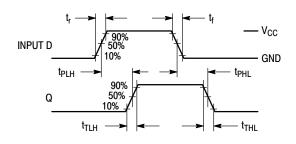
* Used to determine the no-load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

TIMING REQUIREMENTS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6.0 \text{ ns}$)

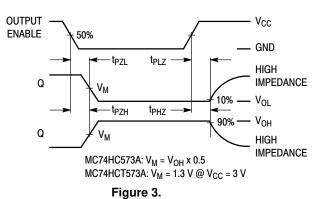
				Guaranteed Limit						
			Vcc	–55 to	25°C	≤ 8	5°C	≤12	25°C	
Symbol	Parameter	Figure	Ň	Min	Max	Min	Max	Min	Max	Unit
t _{su}	Minimum Setup Time, Input D to Latch Enable	4	2.0	50		65		75		ns
			3.0	40		50		60		
			4.5	10		13		15		
			6.0	9.0		11		13		
t _h	Minimum Hold Time, Latch Enable to Input D	4	2.0	5.0		5.0		5.0		ns
			3.0	5.0		5.0		5.0		
			4.5	5.0		5.0		5.0		
			6.0	5.0		5.0		5.0		
t _w	Minimum Pulse Width, Latch Enable	2	2.0	75		95		110		ns
			3.0	60		80		90		
			4.5	15		19		22		
			6.0	13		16		19		
t _r , t _f	Maximum Input Rise and Fall Times	1	2.0		1000		1000		1000	ns
			3.0		800		800		800	
			4.5		500		500		500	
			6.0		400		400		400	

MC74HC573A

SWITCHING WAVEFORMS







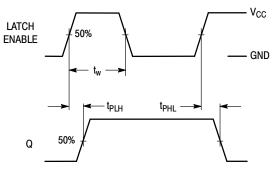
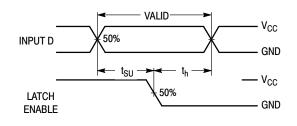
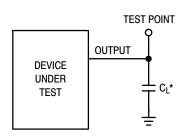


Figure 2.

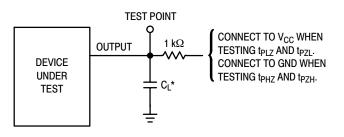






*Includes all probe and jig capacitance





*Includes all probe and jig capacitance



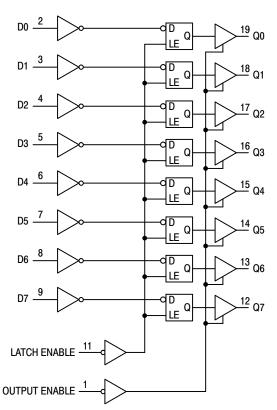


Figure 7. EXPANDED LOGIC DIAGRAM

ORDERING INFORMATION

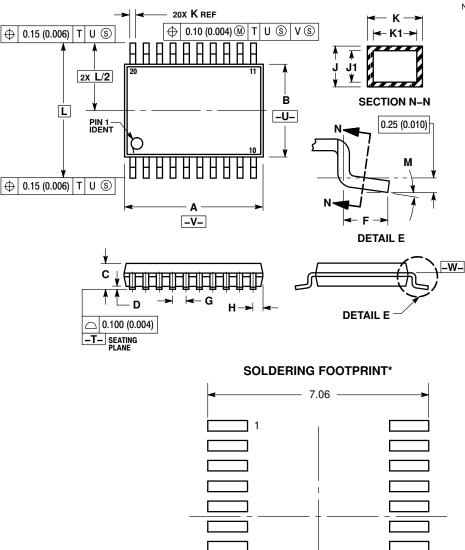
Device	Package	Shipping [†]
MC74HC573ADWG	SOIC-20 WIDE (Pb-Free)	38 Units / Rail
MC74HC573ADWR2G	SOIC-20 WIDE (Pb-Free)	1000 Tape & Reel
MC74HC573ADTG	TSSOP-20 (Pb-Free)	75 Units / Rail
MC74HC573ADTR2G	TSSOP-20 (Pb-Free)	2500 Tape & Reel
NLV74HC573ADTR2G*	TSSOP-20 (Pb-Free)	2500 Tape & Reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP

Capable.

PACKAGE DIMENSIONS

TSSOP-20 **DT SUFFIX** CASE 948E ISSUE D



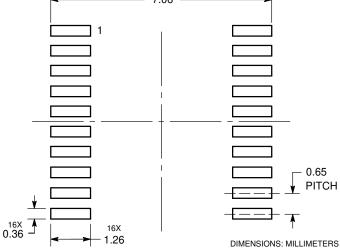
NOTES:

 DTES:
DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: MILLIMETER.
DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (2006) PER SIDE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION

CONDITION. 6. TERMINAL NUMBERS ARE SHOWN FOR

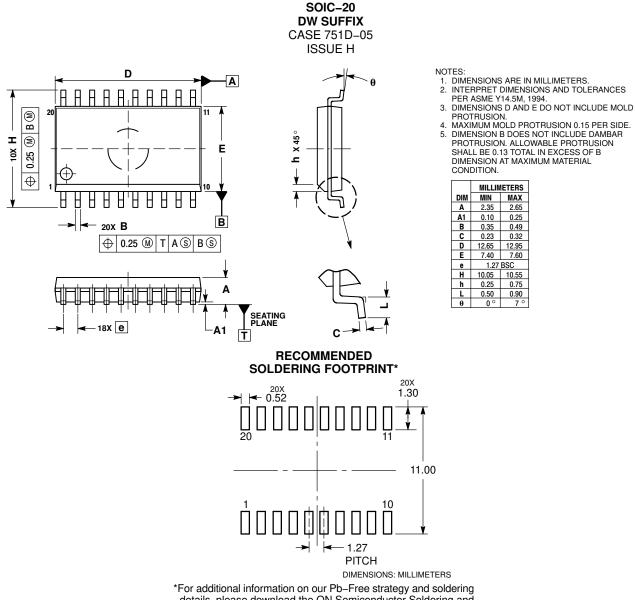
TERMINEL NOMBERS ARE SHOWN REFERENCE ONLY.
DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE – W–.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	6.40	6.60	0.252	0.260	
В	4.30	4.50 0.169	4.50	0.177	
c		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026 BSC		
Η	0.27	0.37	0.011	0.015	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40		0.252 BSC		
М	0°	8°	0°	8°	



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS



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